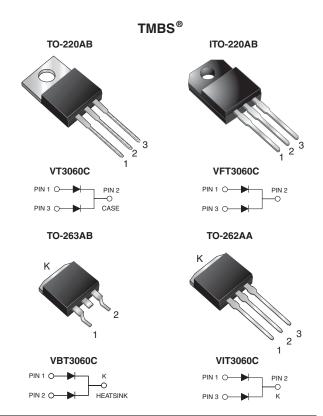
VT3060C-E3, VFT3060C-E3, VBT3060C-E3, VIT3060C-E3

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Dual High Voltage Trench MOS Barrier Schottky Rectifier

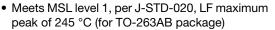
Ultra Low $V_F = 0.38 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V _{RRM}	60 V					
I _{FSM}	170 A					
V _F at I _F = 15 A	0.57 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation





 Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)

 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB, and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	VT3060C	VFT3060C	VBT3060C	VIT3060C	UNIT
Max. repetitive peak reverse voltage	V_{RRM}	60					
Max. average forward rectified current	per device	I	30				
(fig. 1)	per diode	I _{F(AV)}	15				
Peak forward surge current 8.3 ms single half superimposed on rated load per diode	sine-wave	I _{FSM}	170				Α
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH per diode		E _{AS}		mJ			
Peak repetitive reverse current at $t_p = 2 \mu s$, 1 kHz, $T_J = 38 ^{\circ}C \pm 2 ^{\circ}C$ per diode	per diode IR _{RM}		1.0				А
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500				V
Operating junction and storage temperature range			-55 to +150				°C



VT3060C-E3, VFT3060C-E3, VBT3060C-E3, VIT3060C-E3

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	60 (min.)	-	V		
Instantaneous forward voltage per diode (1)	I _F = 5 A	T _A = 25 °C T _A = 125 °C	V	0.47	-	V		
	I _F = 7.5 A			0.51	-			
	I _F = 15 A			0.60	0.70			
	I _F = 5 A		V_{F}	0.38	-			
	I _F = 7.5 A		PC	0.44	-			
	I _F = 15 A			0.57	0.65			
Reverse current per diode (2)	V _R = 60 V	T _A = 25 °C T _A = 125 °C	I _R	-	1.2	mA		
	v _R = 00 v			20	45			

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	VT3060C	VFT3060C	VBT3060C	VIT3060C	UNIT	
Typical thermal resistance	per diode	R _{θJC}	2.5	6.0	2.5	2.5	°C/W	
	per device		1.7	4.8	1.7	1.7	C/VV	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT3060C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VFT3060C-E3/4W	1.76	4W	50/tube	Tube			
TO-263AB	VBT3060C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VBT3060C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VIT3060C-E3/4W	1.46	4W	50/tube	Tube			

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

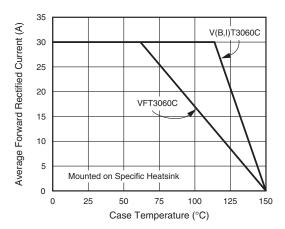


Fig. 1 - Maximum Forward Current Derating Curve

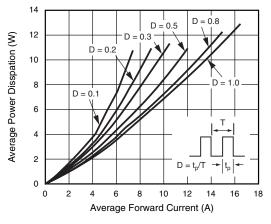


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

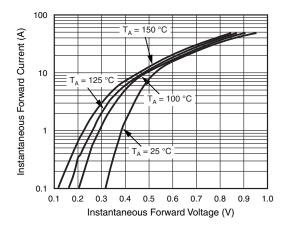


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

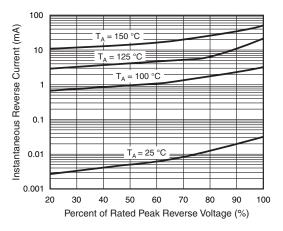


Fig. 4 - Typical Reverse Characteristics Per Diode

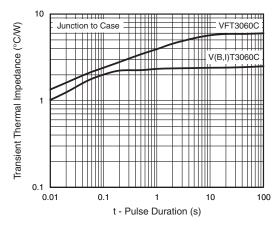


Fig. 5 - Typical Transient Thermal Impedance Per Diode

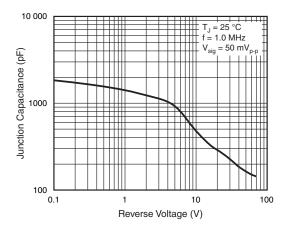


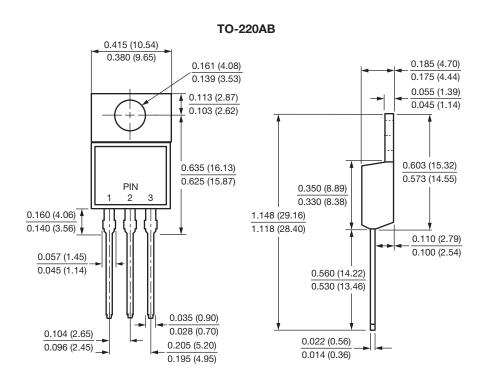
Fig. 6 - Typical Junction Capacitance Per Diode

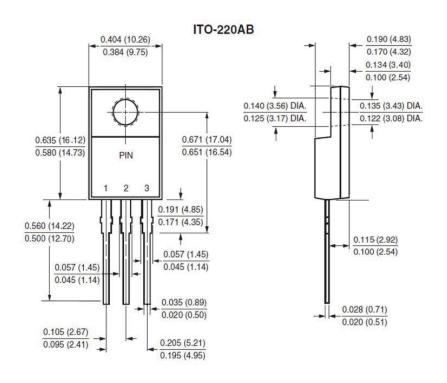


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



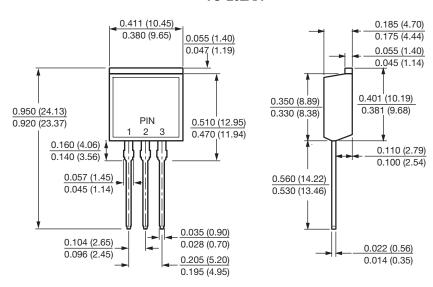


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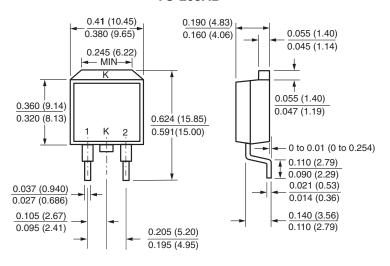
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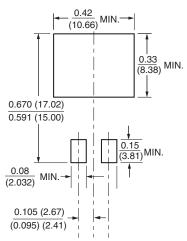
TO-262AA



TO-263AB



Mounting Pad Layout





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